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The invention relates to the semiconductor photography and may be used in holography, for replication of optical (holographic or analogous) information, as well as in the laser nondestructive test methods.

The process for optical information recording includes the exposure of a thin-layer noncrystalline metal-semiconductor structure, for example nickel-As<sub>2</sub>S<sub>3</sub> and further application of an electric field, is created by corona discharge.

Claims: 1

Fig.: 3